

Trans MOSFET N-CH 500V 0.03A 3-Pin TO-92 Bag



Images are for reference only

[Inquiry](#)

Manufacturer: [Microchip Technology, Inc](#)

Package/Case: TO-92

Product Type: Thyristors

RoHS: RoHS Compliant/Lead free 

Lifecycle: Active

General Description

The LND150 is a high voltage N-channel depletion mode (normally-on) transistor utilizing lateral DMOS technology. The gate is ESD protected. The LND150 is ideal for high voltage applications in the areas of normally-on switches, precision constant current sources, voltage ramp generation and amplification.

Key Features

Free from secondary breakdown

Low power drive requirement

Ease of paralleling

Excellent thermal stability

Integral source-drain diode

High input impedance and low CISS

ESD gate protection

Recommended For You

2N3823

Microchip Technology, Inc

CAN

2N6661

Microchip Technology, Inc

CAN3

2N4416A

Microchip Technology, Inc

TO-72

APT60GT60BRG

Microchip Technology, Inc
TO-247B

2N4857

Microchip Technology, Inc
CAN

APT45GR65B

Microchip Technology, Inc
TO-247

APT60GT60JRD

Microchip Technology, Inc
MODULE

2N3822

Microchip Technology, Inc
CAN

JANIX2N6284

Microchip Technology, Inc
TO-3

2N6283

Microchip Technology, Inc
TO-3

APT75GN120LG

Microchip Technology, Inc
TO-264L

APT30GT60BRDQ2G

Microchip Technology, Inc
TO-247

APT100GN60LDQ4G

Microchip Technology, Inc
TO-264L

JAN2N6301

Microchip Technology, Inc
TO-66(TO-213AA)

APT50GF120LRG

Microchip Technology, Inc
TO-264L